



DMTH6010LK3Q

60V 175°C N-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

BV _{DSS}	R _{DS(ON)} Max	I _D Max T _C = +25°C
60V	8mΩ @ V _{GS} = 10V	70A
	$12m\Omega @ V_{GS} = 4.5V$	50A

Description and Applications

This MOSFET is designed to meet the stringent requirements of Automotive applications. It is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

- Engine Management Systems
- Body Control Electronics
- DCDC Converters

Features

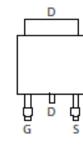
- Rated to 175°C ideal for high ambient temperature environments
- 100% Unclamped Inductive Switching ensures more reliable and robust end application
- Low On-Resistance
- Low Input Capacitance
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

Mechanical Data

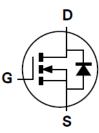
- Case: TO252
- Case Material: Molded Plastic, "Green" Molding Compound.
- UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Finish Matte Tin Annealed over Copper Leadframe; Solderable per MIL-STD-202, Method 208 (@)
- Weight: 0.33 grams (Approximate)



Top View



Pin Out Top View



Equivalent Circuit

Ordering Information (Note 5)

Part Number	Case	Packaging
DMTH6010LK3Q-13	TO252	2,500/Tape & Reel

Notes:

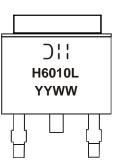
1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.

2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

- 4. Automotive products are AEC-Q101 qualified and are PPAP capable. For more information, please refer to
- http://www.diodes.com/product_compliance_definitions.html.
- 5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



] | | = Manufacturer's Marking
 H6010L = Product Type Marking Code
 YYWW = Date Code Marking
 YY = Last Two Digits of Year (ex: 15 = 2015)
 WW = Week Code (01 to 53)



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage	V _{DSS}	60	V	
Gate-Source Voltage		V _{GSS}	±20	V
Continuous Drain Current, V _{GS} = 10V (Note 6)	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	ID	14.8 11.9	A
Continuous Drain Current, V _{GS} = 10V (Note 7)	$T_{C} = +25^{\circ}C$ $T_{C} = +100^{\circ}C$	ID	70 50	A
Maximum Continuous Body Diode Forward Current (Note 7)	ls	60	A	
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	I _{DM}	130	A	
Avalanche Current, L = 0.1mH	I _{AS}	20	A	
Avalanche Energy, L = 0.1mH		E _{AS}	20	mJ

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Total Power Dissipation (Note 6)	PD	31	W
Thermal Resistance, Junction to Ambient (Note 6)	R _{0JA}	47	°C/W
Total Power Dissipation (Note 7)	PD	60	W
Thermal Resistance, Junction to Case (Note 7)	R _{θJC}	2.5	°C/W
Operating and Storage Temperature Range	T _{J,} T _{STG}	-55 to +175	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

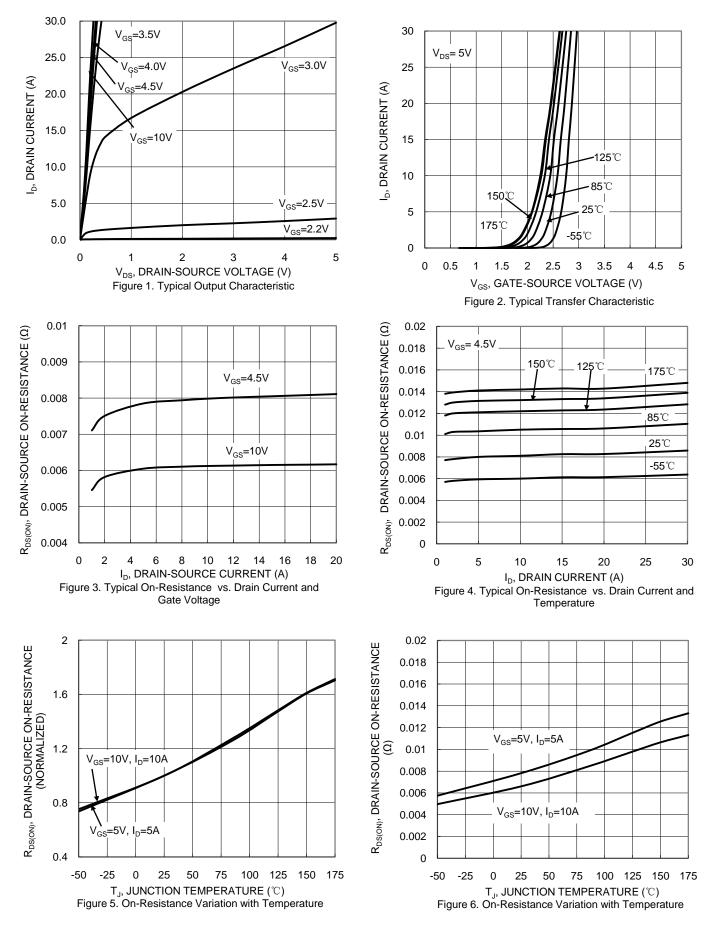
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)							
Drain-Source Breakdown Voltage	BV _{DSS}	60	-	-	V	$V_{GS} = 0V, I_D = 1mA$	
		-	-	1	μA	$V_{DS} = 48V, V_{GS} = 0V$	
Zero Gate Voltage Drain Current (Note 9)	I _{DSS}	-	-	100	μA	$V_{DS} = 48V, V_{GS} = 0V,$ $T_J = 125^{\circ}C$	
Gate-Source Leakage	IGSS	-	-	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 8)							
Gate Threshold Voltage	V _{GS(TH)}	1	-	3	V	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$	
Static Drain-Source On-Resistance		-	6.3	8		$V_{GS} = 10V, I_D = 20A$	
Static Drain-Source On-Resistance	R _{DS(ON)}	-	8.3	12	mΩ	V _{GS} = 4.5V, I _D = 20A	
Diode Forward Voltage	V _{SD}	-	0.9	1.2	V	$V_{GS} = 0V, I_{S} = 20A$	
DYNAMIC CHARACTERISTICS (Note 9)						÷	
Input Capacitance	Ciss	-	2090	-			
Output Capacitance	Coss	-	746	-	pF	$V_{DS} = 30V, V_{GS} = 0V,$ f = 1MHz	
Reverse Transfer Capacitance	C _{rss}	-	38.5	-			
Gate Resistance	Rq	0.1	0.59	1.8	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$	
Total Gate Charge (V _{GS} = 4.5V)	Qq	-	19.3	-		V _{DS} = 30V, I _D = 20A	
Total Gate Charge (V _{GS} = 10V)	Qq	-	41.3	-	-0		
Gate-Source Charge	Q _{gs}	-	6	-	nC		
Gate-Drain Charge	Q _{qd}	-	8.8	-			
Turn-On Delay Time	t _{D(ON)}	-	5.7	-		$V_{DD} = 30V, V_{GS} = 10V,$ $I_{D} = 20A, R_{g} = 3\Omega$	
Turn-On Rise Time	t _R	-	4.3	-			
Turn-Off Delay Time	t _{D(OFF)}	-	23.4	-	ns		
Turn-Off Fall Time	t _F	-	9.7	-		-	
Body Diode Reverse Recovery Time	t _{RR}	-	35.4	-	ns		
Body Diode Reverse Recovery Charge	Q _{RR}	-	38.2	-	$I_F = 20A, di/dt = 100A/\mu s$		

 Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.
 Thermal resistance from junction to soldering point (on the exposed drain pad).
 Short duration pulse test used to minimize self-heating effect. Notes:

9. Guaranteed by design. Not subject to product testing.



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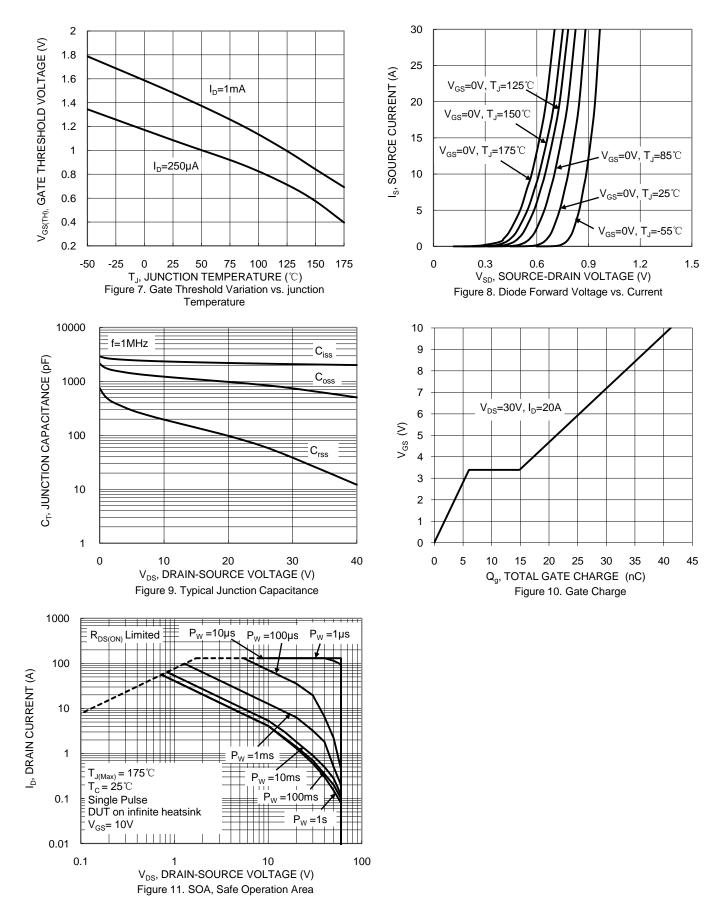


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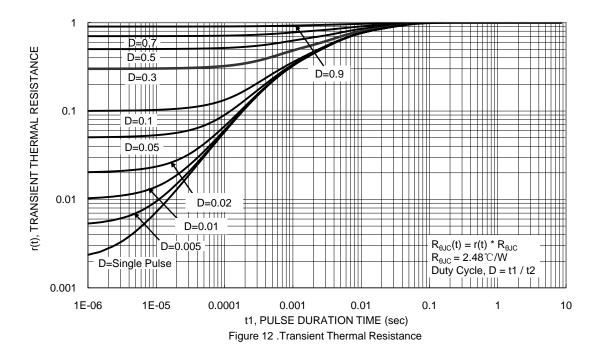
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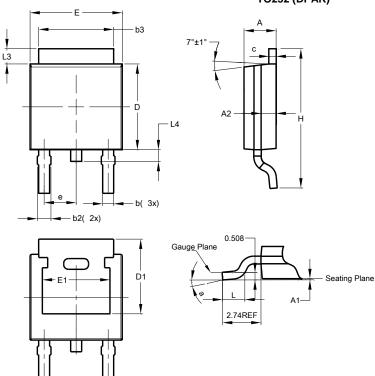






Package Outline Dimensions

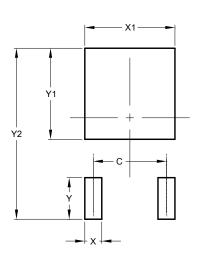
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



TO252 (DPAK)					
Dim	Min	Max	́Тур		
Α	2.19	2.39	2.29		
A1	0.00	0.13	0.08		
A2	0.97	1.17	1.07		
b	0.64	0.88	0.783		
b2	0.76	1.14	0.95		
b3	5.21	5.46	5.33		
С	0.45	0.58	0.531		
D	6.00	6.20	6.10		
D1	5.21	-	-		
е	-	-	2.286		
Е	6.45	6.70	6.58		
E1	4.32	-	-		
Н	9.40	10.41	9.91		
L	1.40	1.78	1.59		
L3	0.88	1.27	1.08		
L4	0.64	1.02	0.83		
а	0°	10°	-		
All	All Dimensions in mm				

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
С	4.572
Х	1.060
X1	5.632
Y	2.600
Y1	5.700
Y2	10.700

TO252 (DPAK)

TO252 (DPAK)



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